

## **ON Semiconductor®**

# **ON Semiconductor** DATA SHEET



## P-Channel Silicon MOSFET 2SJ670 — General-Purpose Switching Device **Applications**

## **Features**

- · Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	١D		-1.5	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	-6	А
Allowable Power Dissipation	Do	Mounted on a ceramic board (600mm <sup>2</sup> ×0.8mm)	1.5	W
	PD	Tc=25°C	3.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-100			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-100V, VGS=0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-0.8A	1.3	2.3		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	ID=-0.8A, VGS=-10V		410	535	mΩ
	R <sub>DS</sub> (on)2	ID=-0.8A, VGS=-4V		530	745	mΩ
Input Capacitance	Ciss	VDS=-20V, f=1MHz		535		pF
Output Capacitance	Coss	V <sub>DS</sub> =-20V, f=1MHz		43		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =-20V, f=1MHz		31		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		9		ns
Rise Time	tr	See specified Test Circuit.		4.5		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		62		ns
Fall Time	tf	See specified Test Circuit.		34		ns

Marking : NA

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	VDS=-50V, VGS=-10V, ID=-1.5A		11		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-1.5A		2.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-1.5A		2		nC
Diode Forward Voltage	VSD	IS=-1.5A, VGS=0V		-0.83	-1.2	V

#### **Package Dimensions**

unit : mm (typ) 7007A-003



### **Switching Time Test Circuit**







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